





Europees Fonds voor Regionale Ontwikkeling

#### FLEXLINES CLOSING EVENT

# FLEXLINES

Enabling an easily accessible regional production facility for flexible electronics.







**Provincie Noord-Brabant** 





#### **PROGRAM**

- INTRODUCTION Dieter Therssen, CEO, DSP Valley
- A WORD FROM THE DIRECTOR OF INTERREG Bram De Kort, Director Interreg Vlaanderen-Nederland
- A WORD FROM THE DEPUTY OF PROVINCE FLEMISH BRABANT Marlies Vanthyune for Ann Schevenels, Deputy Province of Flemish Brabant
- FLEXLINES ONE-STOP-SHOP:
- Romano Hoofman, Program Director, imec





#### **PROGRAM**

- LARGE-AREA SHEET-2-SHEET THIN FILM TRANSISTOR PILOT LINE INFRASTRUCTURE

Auke Jisk Kronemeijer, Senior Researcher & GEN1 TFT Pilot Line Manager, TNO/Holst Centre

- UNDERSTANDING AND IMPROVING TFT PERFORMANCE: Rene Janssen, Professor Molecular Materials and Nanosystems, TU/E

-- 5 min BREAK --

- CIRCUIT DESIGN TECHNIQUES WITH INGaZNO THIN-FILM TRANSISTORS FOR LARGE AREA ELECTRONICS:

Mohit Dandekar, research assistant, KU Leuven





#### **PROGRAM**

- PRINTED ELECTRONICS FOR THERMOFORMING AND INJECTION MOULDING:

Margreet De Kok, Program manager structural electronics, TNO/Holst Centre

- THE EFFECT OF OVERMOULDING ON RELIABILITY OF FLEXIBLE ELECTRONIC CIRCUITS:

Mona Bakr, Researcher, imec CMST

- INJECTION OVER-MOULDING FLEXIBLE ELECTRONICS WITH ENGINEERING THERMOPLASTICS:

Yibo Su, Scientist, Brightlands Materials Center

- CONCLUSIONS / CLOSING REMARKS - ONE-STOP-SHOP REMINDER

Romano Hoofman, Program Director, imec













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#### **Dieter Therssen, CEO DSP Valley**





**Provincie Noord-Brabant** 





# A regional collaboration

#### Objectives

- Expansion of a Flexible Electronics pilot infrastructure. Operationalization of essential production investments and improvement of design and production processes.
- Set-up of a 'one-stop-shop' for the realization of prototypes of Flexible Electronics applications.
- Realisation of a number of demonstrators
  - as the first validation for the deployed design and manufacturing assets
  - as showcases, to inform the ecosystem about the possibilities









## A regional collaboration

valley







Brightlands Materials Center

TU/e





Vlaanderen-Nederland



### breeding digital business



# Flexlines

#### Scope

- Flexlines addresses the entire physical realization part of novel formable electronics and their embodiment in devices.
- Design tools (modeling, simulation), design, fabrication steps, flexible electronics, integration in overmoulded assemblies.











# Flexlines

#### Scope

**Flexlines** 

- Flexlines addresses the entire physical realization part of novel formable electronics and their embodiment in devices.
- Design tools (modeling, simulation), design, fabrication steps, flexible electronics, integration in overmoulded assemblies.



# Flexible electronics projects

Projects contributing technology:



https://smartees.eu/open-call-smartees2/

FLEXLINES OF Vaanderen-Nederland REXIBLE ELECTRONICS PROTOTYPING

https://www.smartx-europe.eu/application/

~1 MIO EUR

cascade funding

## Flexible electronics projects

Into applications that NEED flexible/wearable:











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# **FLEXLINES One-Stop-Shop**

#### Romano Hoofman, imec



#### Easy access to the fabrication of flexible electronics prototypes







# Main objective

"To create a one-stop service, where academia and companies can realize their ideas in flexible and cheap electronics-applications."

- In order to achieve this, the following is needed:
  - Further maturing of the technology,
  - Development of a compliant design process flow,
  - Reaching out to customers for development of new applications.











### What / how / who?

- What will be offered?
- How will it be offered?
- Who is the customer?









# What ?

• TFT process technology











#### Development of a One-Stop-Shop for flexible electronics

#### The "Europractice" concept











### The "Europractice" concept

- Launched by EU in 1995 to enhance European competitiveness in global market – collaboration of several European Research institutes – offering of industrial technologies (not easily accessible for prototyping)
- Facilitate access to Si technologies (ASIC, MEMS and PIC) and packaging
- Multi-project wafer approach to lower prototyping cost
- Access to design tool software (packages) for academics







### **MPW service for flexible electronics**

 Multi-customer project services could also be made available for flexible electronics (*if needed*), such that the fabrication cost can be lowered by sharing multiple customer prototypes on the same production run.











## Who?



#### • In the pilot phase:

- Experienced designers from academic institutions
- After the project:
  - Companies who are (un)familiar with underlying technologies, and their business idea can be realized using these technologies.
    - Additional design support will be offered (at cost)







### Leverage

- FLEXLINES utilizes the already existing ecosystem of the project partners.
  - FLEXLINES benefits from the many years experience of imec IC-link and EUROPRACTICE (the one-stop-shop for traditional ICs, MEMS and Si-Photonics)

















Large-Area Sheet-2-Sheet Thin Film Transistor Pilot Line Infrastructure

Auke Jisk Kronemeijer Program Manager, TNO / Holst Centre







**Provincie Noord-Brabant** 

provincie limburg





**One-Stop-Shop** Partnership Cooperation Model





Core Offer Design & Realization Multi-project FPD Sheets Electronics-on-Foil





- **Optional Offer** 
  - Integration Technologies



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#### **Oxide Transistor Arrays on Plastic**

A Key Enabler of Flexible Electronics

### Holst Centre R&D TFT Technology

• a-IGZO Oxide Thin Film Transistors

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Information Display 36 (3), 9-13 (2020)

MANUFACTURING FACILITY	FAB SIZE
BOE (B17)—Wuhan, China (a-Si:H TFT/oxide + WOLED*)	Gen 10.5
China Star (17)—Shenzhen, China (a-Si:H TFT/oxide + WOLED)	Gen 10.5
Mantix Display Technology—Putian, China (a-Si:H/oxide TFT)	Gen 6
Foxconn/SDP—Kameyama, Japan (oxide TFT)	Gen 6
Foxconn/SDP—Kameyama, Japan (oxide TFT)	Gen 8
LG Display (E2)—Paju, South Korea (LTPO)	Gen 4.5
LG Display (P8)—Paju, South Korea (oxide TFT)	Gen 8.5
LG Display (P9)—Paju, South Korea (oxide TFT)	Gen 8.5
LG Display—Guangzhou, China (oxide TFT)	Gen 8.5
LG Display (P10)—Paju, South Korea (oxide TFT)	Gen 10.5
Panda—Nanjing, China (oxide TFT)	Gen 8.5
Panda—Chengdu, China (oxide TFT)	Gen 8.6+
Royole—Shenzhen, China (oxide + OLED)	Gen 5.5
Samsung (A2)—Asan, South Korea (LTPO)	Gen 5.5
Foundry or development facility	
dpiX—Colorado Springs, Colorado	
Flexible Electronics & Display Center—Tempe, Arizona	
Holst Centre—Eindhoven, Netherlands	
Semiconductor Energy Laboratory—Kanagawa, Japan	

Amorphous n-type Oxide Semiconductor with Increased Install-Base and Existing Products on Display Market



#### **Application Prototyping Platform**

- Flexible Displays
- Flexible Imagers
- Flexible Circuitry









### **R&D Pilot Line: Size & Applications**

- 320x352 mm Glass Substrates
- Temporary Bonding of Laminated or Spin-on Foils for Flexible Electronics
- a-IGZO Semiconductor
- FPD-compatible Processes
- Mechanical & Laser Debonding
- Prototypes:
  - Displays
  - Imagers
  - Circuits







### **Scalable to Mass Manufacturing**

• Flat Panel Display Fabrication Plants















#### **Holst Centre R&D Pilot Line Facilities**



## Flexlines: New Infrastructure (1)

- Centralisation of TFT Process Flow in Eindhoven
  - Move a-IGZO Sputtering from Leuven (BE) to Eindhoven (NL)
- Installation & Release of New 32 x 35 cm Sputter Tool
  - 2 Chambers, 4 Targets
    - a-IGZO
    - ITO
    - MoCr
    - AlTi
- No Transport Leuven / Eindhoven Needed
  - Batch Throughput Time Decreased by 1 Week











## Flexlines: New Infrastructure (2)

- Centralisation of TFT Process Flow *within* Eindhoven
  - Transfer of PECVD Process from Philips Innovation Services to Holst Centre
- Installation and Release of New 32 x 35 cm PECVD Tool
  - European Tender, Unforeseen Court Case, Assembly at Supplier, Installation at Holst Centre
  - Process Release Delayed due to Court Case and Corona

(PInS Decommission as Planned, No PECVD Q4 2020 – Impacting Flexlines)















# Implementation of Process Monitoring & Technology Improvement

- Implementation of Six Sigma Methodology
  - Black Belt / Green Belt Courses for Pilot Line Employees







# Implementation of Process Monitoring & Technology Improvement

- Implementation of Six Sigma Methodology
  - Creation of Monitoring Dashboard









# Implementation of Process Monitoring & Technology Improvement

- Implementation of Six Sigma Methodology
  - Creation of Monitoring Dashboard






# Implementation of Process Monitoring & Technology Improvement

PECVD Tool: Clean + Decide on Way of Working

- Implementation of Six Sigma Methodology
  - Improvement Baseline Technology







# **Flexlines Portfolio**

• TFT Technology Employed for the Realization of Prototypes



Providing Companies in the Flanders – Netherlands Region with Access to these Technologies for Prototyping



# **Flexible AMOLED Displays**









#### **Flexible X-Ray Detectors**











### **Transparent Fingerprint Scanners**









#### **Near-Infrared Vein Detectors**







### **Electronic Tags in Paper**









#### **Injection Moulded Circuitry & Components (1)**







#### **Injection Moulded Circuitry & Components (2)**









Electronics, Graphics & Component Assembly

Overmoulding of Flex-Foils

**Finalized Part** 



# **Thermoformed Imager Arrays**

2 10 4 70 60 OPD photodetector array on glass Amplitude

Curved thermoformed array

Read-out of curved sheep using 2D OPD array



Imaging of curved sheep within 2D OPD array

# **In-Textile Displays**





### **Smart Multiwell TEER Plates**









One-Stop-Shop Partnership Cooperation Model





Core Offer Design & Realization Multi-project FPD Sheets Electronics-on-Foil





- **Optional Offer** 
  - Various Integration Technologies



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#### **Understanding and Improving TFT Performance**

#### René Janssen, Wentao Huang & Tamer Dogan Eindhoven University of Technology





### Main results

New infrastructure

- Set-up for photothermal deflection spectroscopy (PDS) measurements
- Set-up for sub-band gap photocurrent measurements
- Automated set-ups for variable temperature semiconductor characterization

New achievements

Aim: Enhance current drive/switching rate by enhancing mobility or reducing channel length

- Indium-gallium-zinc oxide (IGZO) thin film transistors with ultra thin (< 10 nm) layers
- 1000-Pixels per inch transistor arrays using multi-level imprint lithography



#### Infrastructure

PDS IGZO sub-gap states





Photocurrent

IGZO sub-gap states



### Atomic layer deposition of indium-gallium-zinc oxide

Amorphous **IGZO** is widely used in industry for standard backplane electronics due to its attractive properties such as high electron mobility/good uniformity/low leakage current/low fabrication cost/large-area scalability

**Low-dimensional IGZO** is particularly of interest since devices with dimension close to the carrier accumulation layer enable a completely depleted transistor channel and could potentially overcome the intrinsic bulk mobility limitation

Therefore, **atomic layer deposition**, rather than the most widely-used sputtering technique, is investigated in IGZO film fabrication as the former could provide more precise control of film composition and thickness



### Spatial atomic layer deposition

Atomic layer deposition (ALD) is a gas phase deposition technique which enables digital control of film thickness and composition with excellent conformality on nonplanar surfaces.

In spatial ALD (**s-ALD**) different precursor injection and reaction steps are separated spatially instead of temporally so that the requirement of time-consuming purge steps can be eliminated.



A schematic of the spatial ALD concept



### Spatial atomic layer deposition

Metal precursors (DEZ, TMI, TEG) are pre-mixed before injection and plasma source is used to enable the growth of oxide at low temperature and short exposure times to the oxygen precursor.



Growth per cycle (GPC) vs exposure time & thickness vs number of cycles



### Electrical characterisation of IGZO TFTs by s-ALD





The transfer curves of the transistor exhibit good operating and hysteresis-free characteristics with a high electron mobility of  $\sim 10 \text{ cm}^2/\text{Vs}$ .

The output curve of the same transistor shows excellent output characteristics with a steep rise in the low  $V_D$  region.







# Thickness scaling of IGZO TFTs

The TFT measurement indicates no effect on charge transport for IGZO thickness from 15 nm to 7 nm, but a formation of degenerate transistor channel for thickness down to 3 nm.





# TFT $R_{\rm C}$ analysis by TLM

Contact resistance  $(R_c)$  of the IGZO TFTs is evaluated by transfer-length method (**TLM**)

TFTs with different values of *L* are scanned in the linear regime to extract the intercept of TLM plot, which can be used to qualify  $R_c$ . The results show very small  $R_c$  (~100  $\Omega$ ·cm) for thickness from 15 to 7 nm.

In contrast, TFT with 3 nm IGZO exhibits high  $R_{ON}$  and L independence in the TLM plot, indicating that the 3 nm IGZO device suffers from large  $R_{C}$ 





### Substrate conformal imprint lithography

- Need for high-resolution cost-effective methods to fabricate TFTs over large areas
- Photolithography can deliver line/space patterning resolution of 1-2 μm
- Multi-level imprint lithography potentially combines precision patterning with large-area cost effectiveness
- Employ substrate conformal imprint lithography (SCIL) to realize IGZO TFTs with sub-micrometer channel length in high-density arrays.



# TFT fabrication via multilevel imprint lithography



Resist structure height differences of 0.5 µm in 3D.

Reactive ion etching of residual resist Wet and dry etching

Reactive ion etching

Removal of gate M metal & insulator, S Doping of exposed O IGZO

Metallization of source and drain contacts



#### $\alpha$ -IGZO TFT characteristics





### 1000 ppi $\alpha\text{-IGZO}$ backplane array of 0.8 $\mu m$ TFTs



T. Dogan, IEEE Electron Device Lett. **2020**, *8*, 1217–1220.

Typical transfer curves of  $\alpha$ -IGZO TFTs (*W*/*L* = 1.2/0.8  $\mu$ m) in the array.



### Conclusions

- IGZO films by s-ALD fabricated and characterized in TFT architecture. The results benchmark the performance of s-ALD IGZO TFTs fabricated in ESL architecture.
- Thickness scaling experiment was performed to explore the feasibility of low-dimensional IGZO TFT by s-ALD.
- Functional IGZO device with thickness down to 7 nm, but device with 3 nm exhibits a considerably large R<sub>c</sub>. Possibly related to roughness dielectric or kick start ALD growth
- 1000 ppi TFT backplane arrays with sub-micrometer α-IGZO top-gate self-aligned thin-film transistors using multi-level imprint lithography down to channel lengths of ~700 nm.
- The α-IGZO transistors switch on close to 0 V and have mobility ~10 cm<sup>2</sup> V<sup>-1</sup> s<sup>-1</sup>, similar to photolithography-benchmark devices.









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# Flexlines project WP5: Integrate flexible electronics with engineering thermoplastics by injection over-molding



Adri van der Waal, Bart Peeters, Albert van Breemen, Auke Kronemeijer, Margreet de Kok 10<sup>TH</sup> dec 2020 Flexlines closing event: webinar TNO / Holst Centre





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provincie limburg



# Hybrid printed electronics for integration

- Background of challenges for electronics in thermoforming and injection moulding
- Two examples of technology developed in pilot line:
  - 1. Overmoulded hybrid printed electronics
  - 2. Thermoformed hybrid electronics









#### Flexlines

#### TNO at Holst Centre: freeform electronics by printed electronics

#### electronics today



• Limited formfactor - rigid

**Flexlines** 

#### electronics tomorrow



• **New formfactors** - *flexible, stretchable, structural* 



#### Hybrid printed electronics

#### **Roll-2-roll screen printing**



#### **Roll-2-roll component assembly**



#### **High Pressure Thermoforming**







#### Development of structural electronics



All process steps are strongly inter-linked...

#### Flexlines



# Challenges for integration

#### **Thermoforming**

- Temperature (160 °C for PC)
- Pressure (60 100 Bar)
- Deformation

#### Resulting in:

- Disconnection of components
- Thermal shock and damage to electronics





#### Injection moulding

- Temperature (260 °C for PC-resin)
- Pressure (<200 Bar)

#### Resulting in:

- Disconnection of components
- Thermal shock and damage to electronics
- Wash-out of graphics and electronic tracks







#### **Flexlines**

# Example 1: Overmoulded hybrid printed electronics:





Fluid velocity distribution in mold

• Washout of graphics

**Flexlines** 

- Washout and disconnection of electronics
- Adhesion between layers
- Wrinkles in injection moulded part



72
### Integration by injection moulding

Overmoulding is performed with a semi-circular mould, designed by BMC – TNO. In this mould, the flexible substrate is bent in one direction







### Functional demonstrator



Functionalities:

- Capacitive touch
- LED integration





# Example 2: Thermoformed hybrid electronics:

- Photodetector array laminated onto PC and then thermoformed
- Challenges: temperature sensitive OPD and deformation in TF process





### Temperature and pressure sensitivity of OPD





### Thermoformorming of OPD on PC







- Processing in High Pressure Forming machine (Niebling)
  - Heating time 13.5 s
  - Maximum temperature substrate (PC) 160 °C
  - Pressure 80 bar
  - Mould temperature 120 °C





### 16x16 OPD array after thermoforming







### Characterisation of dark current



After PC lamination

After laser delamination



Х



### Characterisation in light (110 Cd/m<sup>2</sup>)



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Interreg
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### Angle dependency : light intensity in Cd m<sup>-2</sup>





### Conclusions

- Technology developed for thermoforming and injection moulding of hybrid printed electronics
- Pilot line established with Flexlines partners
- Use case examples of light generation with sensors and imagining functionalities realised











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# Injection over-molding of flexible electronics with engineering thermoplastics

### Yibo Su, Ali Rezaei, Amandine Codou, Marc Huisman

### **TNO-Brightlands Materials Center**



**Provincie Noord-Brabant** 





# Introduction

Integrating flexible electronics into injection over-molded parts can be used to fabricate a lightweight structural component with integrated functionality (e.g. sensor, structural health monitoring, display)



Step 1: Printing electronics on a flat foil to form the circuit



Step 2: Pre-forming the flexible foil circuit



Step 3: Injection over-molding with high stiffness and strength engineering thermoplastic



- **1.** Final product fulfills certain structural requirements
- 2. Utilizing adhesion between foil and thermoplastic to offer significant design freedom



Video: The automated injection over-molding process suitable for multiple flexible electronics – engineering thermoplastics systems







Brightlands Materials Center





### **Goal and approach**

**Goal:** A technical demonstrator with significant curvature (semi-circle) to demonstrate the design freedom provided by flexible electronics, which can be fabricated by different material systems:

- Engineering thermoplastics:
  - Polypropylene (PP), Polyamide (PA), Polycarbonate (PC)
  - With and without glass fiber reinforcement
- Two types of base foil for the flexible electronics:
  - Transparent: Polyethylene naphthalate (PEN) and Polycarbonate (PC) with silver printed connections
  - Non-transparent: Polyimide (PI) with copper cladded circuit



PEN foil + PC



PI foil + PA

Challenges in designing and manufacturing of such a demonstrator:

- 1. High strength engineering thermoplastics usually requires high processing temperature and pressure:
  - Approach: Understand the effect of these processing parameters on performance of electronics by advanced simulation technology.
- 2. Engineering thermoplastic and base foil of flexible electronics are dissimilar materials.
  - Approach: Optimize the adhesion between engineering thermoplastic and base foil with modified interface material and processing.
- 3. The long-term performance of such injection overmolded flexible electronics under certain environmental condition is unknown.
  - Approach: Evaluate the performance of the injection over-molded flexible electronics with accelerated environmental aging test, both in functionality and adhesion.



### Understanding temperature and stress of electronics in injection overmolding by applying advanced simulation technology



Example: Simulate temperature and stress on different locations within the mold cavity in the cavity filling process



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### Adhesion between foil and engineering thermoplastic

- Polycarbonate (PC) and Polyethylene naphthalate (PEN) based foil: Over-molded with PC thermoplastic offers good adhesion.
- Polyimide (PI) based foil: Traditionally, PI is used as release film in thermoplastic processing, thus proper coating required.





### Long-term reliability test of over-molded electronics

#### Materials

PI foil - PA and PI foil – Glass fiber filled PA

#### 2 Test steps

- Aging samples under 80 °C/-40 °C fluctuations for 30 cycles according to ISO 16750-4
- After checking cyclic aging, aging samples under 85°C/85% RH for 3000 h, which equals to approx. 100 years in 35°C/60% RH.

#### Study tools

Flexible PI foil with printed LEDs is over-molded with a "tensile test specimen" bar shape product, see figure



#### LEDs before aging



#### LEDs after aging

#### **Conclusion:**

- All of the LED samples printed on PI foils over-molded by both PA6 and GFPA6 retain their function after cyclic aging (Step 1) and 3000h static aging (Step 2).
- Adhesion between PI foil and GFPA6 is even improved after aging due to the high temperature further promote chemical bonding.



# Summary and conclusion

- It is possible to well integrate flexible electronics into complex shaped engineering thermoplastic injection over-molded parts while retaining the functionality of electronics in long term use.
- The process of injection molding can be optimized through:
  - Suitable material treatment to achieve good adhesion.
  - Simulated electronic component temperature and stress to formulate an optimized circuit design.









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Prof. Wim Dehaene (KUL)

Dr. Kris Myny (imec)

Prof. Jan Genoe (imec/KUL)

**KU LEUVEN** 

**SMART HUB** 

unec

### **Circuit Design Techniques with InGaZnO Thin-Film Transistors for Large Area Electronics**

Mohit Dandekar, PhD Student, MICAS-ESAT KU Leuven

> eren Voor ieder van ons Provincie Noord-Brabant Provincie Noord-Brabant provincie limburg gesubsidieerd door de Provincie Limburg

# Technology overview

	Amorphous silicon	Organic	Amorphous metal-oxide IGZO	Low-temperature polycrystalline silicon	Crystalline silicon
Charge carrier mobility [cm <sup>2</sup> /Vs]	0.5	0.5-1.0	~10	~100	~1000
Bias stability	Poor	Poor	Reasonable	Good	Good
Max. process temperature	350°C	100°C	350°C	450+°C	800+°C
Carrier type	n-type	p-type n-type possible	n-type	CMOS	СМОЅ
Leakage current	Reasonable	Reasonable	Excellent	Poor	Reasonable
Critical dimension scalability	Excellent	Poor	Good	Poor	Excellent
Mask steps	4-5	4-5	4-5	6-9	18-20
	1	Thin Film <sup>-</sup>		Standard Silicon	
				FLEXILIN	ES OF Interreg

### IGZO-TFTs

Historical Development and Use  $\rightarrow$ 

- Current drive switch in display pixels
- Smaller, faster and less-leaky replacement for a-Si TFT in display technology<sup>\*</sup>

Our Objective → Fully Integrated Circuits and Systems on Foil

Device  $\rightarrow$  Ciruit Blocks  $\rightarrow$  Functional Blocks  $\rightarrow$  Integrated Systems

\* Lorenz et. al., The 2016 Oxide Electronic Materials and Oxide Interfaces Roadmap. Journal of Physics D Applied Physics. 49. 433001. 10.1088/0022-3727/49/43/433001



# Circuit Design with IGZO-TFTs

Flexlines Pilot Line  $\rightarrow$  Dual Gate and Self Aligned Device

- MOS-FET type device
- Semiconductor thin film sandwiched between *two* gates
- Drain-Source symmetric operation
- Dual-Gate coupled channel control

#### Main Challenge → Unipolar Device





#### **DC Drain Current Characteristics**

Interreg

### Circuit Design with IGZO-TFTs

CMOS circuit design  $\rightarrow$  matured research field, But.... No Complementary (P-Type) Device in IGZO  $\rightarrow$ 

- How to make PUN
- How to make loads for gain stages

Solutions (Basic)  $\rightarrow$  Use Ratioed Device

• Dual-Gate operation opens additional possibilities



### New Design Solutions -- Digital

Solutions (Basic+) → Enanced CrossOverLogic

- Based on input triggerred positive feedback
- Makes full use of dual gate operation
- Taped and measured April 2019



Vin [V]

Vin [V]

Original COL -- "F De Roose, J Genoe, W Dehaene, K Myny IEEE Solid-State Circuits Letters 2 (7), 49-52"



### New Design Solutions -- Analog

Solutions (Basic+) → Two Stage Opamp

- Internal output feedback to increase impedance
- Makes full use of dual gate operation
- Taped and measured March 2020







Measured Open Loop Response





# Device Modeling

Advanced Design  $\rightarrow$  Need better device models

- Test structures taped to measure device parameters
- Measurement of small signal parameters under bias
- Hybrid Model based on normalized operating point tables





CV and small signal parameter measurement

Interreg

### Semi-custom TFT design flow





### Conclusions

- Main Challenge  $\rightarrow$  Unipolar device circuit design
- Research Results
  - Use the unique dual-gate channel control to full benefit
  - Improve basic ratioed design with dual gate feedback
  - Prototype designs validated with tapeout and measurement
  - Test structures for measuring device parameters
    - Small signal parameters extracted via direct measurement
  - Development of custom design tool flow at imec Leuven









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### **Electronics in the moulding process**

Mona Bakr, Frederick Bossuyt and Jan Vanfleteren

**CMST-Ghent university & Imec** 





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### CMST facts

- Research Group Center for Microsystems Technology
- Situated on the Technologiepark in Gent-Zwijnaarde
- Affiliated lab with imec and Ghent University
- Research group of ~ 50 people
- CMST is designing and developing microsystems such as implantable devices, smart contact lenses, optical sensors and devices for IoT





### Introduction

What is injection moulding (IM)? – The technology to integrate electronics into plastics:

- Molten plastic is forced into a mould cavity under high pressure to make highly complicated parts at a near net shape with low part costs
- Process:

Material preparation  $\rightarrow$  Feeding into the hopper  $\rightarrow$  injection  $\rightarrow$  Mould holding and cooling  $\rightarrow$  Ejecting

- Can be used in temperature monitoring in molds, wearables and automotive industries.
- Types:
  - Insert moulding
  - In-Mould labelling and In-mould decoration
  - Over-moulding



### Introduction

Both technologies integrate and encapsulate printed electronics and standard electronic components within injection-moulded plastics.

#### Available technology -In mould

- A pre-printed label or decorated film is inserted into the open mould , and held in place with vacuum ports, where vacuum/thermoforming takes place
- Steps: Printing, surface mounting, thermoforming and injection moulding.
- Stacks of : Materials PC, functional inks and electronic components

#### CMST-OVM

- A single part is created using two or more different materials in combination. Typically the first material, sometimes referred to as the substrate, is partially or fully covered by subsequent material (over-mould material)
- Steps: Etching, surface mounting and injection moulding
- Based on polyimide flexible circuits technology





### Aim of work

• Realize electronic circuits on PI-Cu foil in combination with over-moulding

Challenges:

- 1. Obtaining a good adhesion between foil and injection moulded plastics.
- 2. Optimizing the injection moulding process so that the hybrid electronic circuits are not damaged.
- Reliability tests and definition of functional requirements

Challenges:

To maintain the functionality of the electronic circuits (e.g. continuity of connections between components and printed foils)


#### Process flow Over-moulded integrated foils







- Various techniques and PI foils types were used to optimize the adhesion.
- Three types of foils were patterned:
  - 1. Epoxy based adhesive foil
  - 2. Adhesive-less foil
  - 3. Acrylic based adhesive foil
- The chosen foil must meet these conditions:
  - 1. Adhesion between used foil and the injected plastic
  - 2. Electrical conductivity
  - 3. Ability to withstand over-moulding conditions (pressure and temperature)







• Three types of foils were patterned:



	Epoxy based adhesive foil	Adhesive-less foil	Acrylic based adhesive foil
Adhesion:	Good	Worst	Best
Peel force(N) Interfacial fracture energy G <sub>i</sub> (J/m <sup>2</sup> )	9.16 N 514 J/m <sup>2</sup>	0.26 N 175 J/m²	15.2 N 703 J/m²
Conductivity	Almost no data Foils were ripped after ovm	Showed data ,yet fluctuating high values	Values are more in the tolerance range
Withstand process	No	Yes	Yes









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Conductivity	Almost no data Foils were ripped after ovm	Showed data ,yet fluctuating high values	Values are more in the tolerance range
Withstand process	No	Yes	Yes













- The process flow for flexible printed electronic includes patterning the copper structure on a flexible polyimide (PI) substrate via lithography and wet etching followed by an OSP treatment to protect the patterned copper from oxidation.
- Traditional lead free solder and under-fill materials were used.
- For technology check  $\rightarrow$  Resistor foils.
- For technology realization  $\rightarrow$  NFC circuitry demo.
  - $\rightarrow$  RGB matrix demo.







- The integrated foil is clamped in the mould cavity then OVM process is performed where the polymer starts filing the mould and achieving the desired shape.
- OVM conditions: Melt Temperature 270°C Mold temperature 80 °C











- Using two-probe method.
- Connection check was done for 24 resistors before and after over-moulding.
- The overall resistance performance showed no difference between components size and resistors rotation.







- When the length increases the resistance increases in tolerance range of  $0-\Omega$  resistors.
- The data also shows that the mean value is 0.5  $\Omega$ .
- No difference was detected between the package sizes of the components.
- The rotation of the component in the flat mold didn't influenced the measurements.
- After over-molulding, the resistance increases with increasing the temperature.

Foil	Resistor Number	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	21	22	23	24
	Resistance before																								
	OVM (ohms Ω)	0,4	0,5	0,5	0,5	0,5	0,6	0,4	0,4	0,4	0,4	0,5	0,5	0,4	0,5	0,5	0,6	0,6	0,6	0,4	0,4	0,4	0,5	0,5	0,6
	Resistance after																								
1	OVM (ohms Ω)	0,5	0,5	0,5	0,5	0,6	0,6	0,4	0,5	0,5	0,5	0,5	0,5	0,5	0,5	0,5	0,6	0,6	0,6	0,5	0,5	0,5	0,5	0,5	0,7
	Resistance before																								
	OVM (ohms Ω)	0,5	0,5	0,5	0,6	0,5	0,6	0,4	0,4	0,4	0,4	0,5	0,5	0,4	0,5	0,5	0,6	0,7	0,7	0,4	0,5	0,5	0,5	0,5	0,5
	Resistance after																								
2	OVM (ohms Ω)	0,5	0,5	0,5	0,5	0,6	0,6	0,4	0,4	0,4	0,5	0,5	0,5	0,5	0,5	0,5	0,6	0,7	0,8	0,4	0,5	0,5	0,5	0,5	0,5
	Resistance before																								
	OVM (ohms Ω)	0,4	0,5	0,6	0,6	0,6	0,7	0,4	0,4	0,5	0,5	0,5	0,6	0,5	0,5	0,5	0,5	0,5	0,6	0,4	0,4	0,4	0,4	0,4	0,5
	Resistance after																								
3	OVM (ohms Ω)	0,5	0,5	0,6	0,6	0,6	0,7	0,4	0,4	0,5	0,5	0,6	0,6	0,4	0,4	0,5	0,5	0,6	0,6	0,4	0,4	0,4	0,5	0,5	0,5
	Resistance before																								
	OVM (ohms Ω)	0,5	0,5	0,5	0,5	0,5	0,6	0,4	0,4	0,4	0,5	0,4	0,5	0,4	0,4	0,6	0,6	0,6	0,6	0,4	0,4	0,4	0,5	0,5	0,5
	Resistance after																								
4	OVM (ohms Ω)	0,5	0,5	0,6	0,6	0,7	0,8	0,4	0,4	0,4	0,5	0,5	0,5	0,5	0,6	0,7	0,6	0,6	0,6	0,4	0,4	0,4	0,5	0,5	0,5







- The technology is shown by the realization of a demonstrator, in which LEDs are wirelessly powered using an NFC antenna and a chip.
- The NFC antenna is executed in the copper layer and the LEDs and NFC chip are soldered on the foil.
- The antenna and NFC chip can harvest the energy from (e.g. a smartphone) in order to power the LEDs.
- After over-moulding  $\rightarrow$  All LEDs are functional.







- To check the influence of a curvature mould on the components.
- The design is as follows:
  - 20 components in 90° orientation
  - Resistors and LEDs in (1206,0402) packages can be used











- Our design is as follows:
  - Matrix of RGB LEDs connected with a board to show logos as a display
  - As a preliminary testing a column of LEDs is assembled to check the connection to the board and to check the over-moulding.
  - Final demo will be finished in the coming weeks.









### Conclusions

- Preliminary functional test circuits proved that their electronic interconnections can withstand both thermal and mechanical stresses provided from the over-molding process.
- Adhesion was achieved between PI/Cu foil and PA6 as an injected plastic.
- Reliability of these test structures showed good performance on long term application.









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# **FLEXLINES**



### **Concluding remarks**







## Conclusions

- FLEXLINES has proven to be a fabrication route, where academia and companies can realize their ideas in flexible and cheap electronics-applications.
- For more information:
  - FLEXLINES pilot line :
  - One-Stop-Shop:

- Auke.Kronemeijer@tno.nl
- Romano.Hoofman@imec.be











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# FLEXLINES

Flexible Electronics is a technology that offers huge growth potential.

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INTEGRATION OF ELECTRODE ARRAYS IN MICROTITER PLATES

Biochemical experiments are generally performed in standardined microartier wellplates according to AASU/SISS standards. Therefore, integrated electronic treadout of microbiological waters takes to be rendered compatible with these standards. Rednest realized a number of protocype elementations have been realized for the introduction on Nata Destroid Arms (MicRay and Jan and Jan and Arms). Active Matrix Rectirede Arms/ inter (3D protect) CoO microates plates that a done will or interands electroide Arms/ energy eleman states and a state of a prostructurer in between the electroide pads - has been demonstrated by malesized of subjected the electroide arms in multiwells, enabling hully 3D prown-bit less a Anualid the electroide strays.

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#### FLEXLINES ENABLING FLEXIBLE ELECTRONICS PROTOTYPES

Fleximes has developed and coordinated the individual links in the Flexible Electronics value chain processes and infrastructure for design and production. The consortium of partners set up a state-of-the-art and stable pilot line and a 'one-stop-shop for the realisation of Flexible Electronics prototypes.

Prototypes that meet the needs of the local industry in the border region have been realised for validation of the technology. The main prototypes are showcased in this fiyer.









